

WS2994A Fast turn-off Dual LLC Synchronous Rectifier Controller

Description

WS2994A is a high performance dual channel synchronous rectifier controller, which is applied to the output side rectifier of half bridge LLC resonant converter, and can realize the optimal control of MOSFET. By detecting the Vds voltage of the rectified MOSFET, the MOSFET can be reliably switched on and off, thereby replacing Schottky diodes and improving the efficiency of the half-bridge LLC converter.

WS2994A Gate voltage can be regulated according to output load with different turn-on delay time, avoiding false turn-on because of capacitive current during light load.

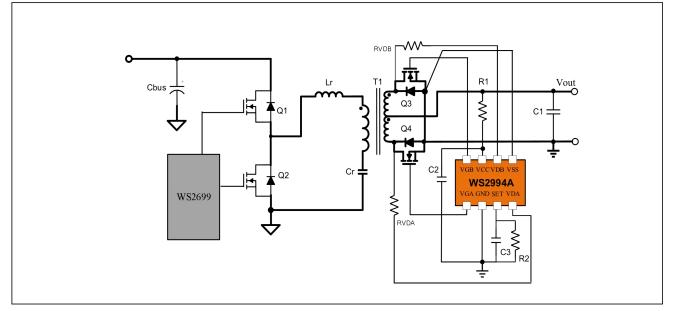
The WS2994A is Green, when the load current reduce to a certain level, the gate drive is turned off, thus limiting the IC current to less than 140uA. The fast shutdown capability of the WS2994A supports continuous conduction mode (CCM) and discontinuous conduction mode (DCM) operation. It is highly-integrated with SOP-8 package.

Features

- VDA, VDB can withstand 120V
- Wide VCC Operation Range, Support 4.83V ~ 35V
- 140uA Low Quiescent Current in Light Load Mode
- Fast Turn-Off ,Support CCM/CrCM/DCM
- High level up to 11.5V for Driver
- Interlock function for Channel A&B
- SOP-8 Package

Typical Application

- AC/DC Adapters
- PC Power Supply
- LCD TV Power Supply
- Industry and Medical Power Supply

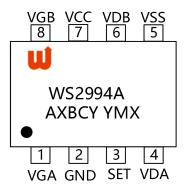


Note: VDA\VDB must be connected with resistance, recommended value: 200Ω -- 2.0kΩ, two resistance values can be different.

Typical Application Circuit

Pin Configuration and Marking Information

WS2994A is available in SOP-8 package. The top marking is shown as below:



| WS2994A: Product Code | | | | | | |
|-----------------------|--|--|--|--|--|--|
| A: Product Code | | | | | | |
| X: Internal Code | | | | | | |
| BCY: Internal QC Code | | | | | | |
| YMX: D/C | | | | | | |

Ordering Information

| Package | Marking | Part Number |
|---------------------|---------|-------------|
| 8-Pin SOP-8,Pb-free | WS2994A | WS2994A |

Absolute Maximum Ratings⁽¹⁾

| Parameter | Limit | Unit |
|---|----------|------|
| VCC to VSS | -0.3~38 | V |
| GND to VSS | -0.3~0.3 | V |
| VGA,VGB to GND | -0.3~20 | V |
| VDA, VDB to to VSS | -0.8~120 | V |
| SET to VSS | -0.3~6.5 | V |
| Power Dissipation ⁽²⁾ (Ta=25 °C) | 1.4 | W |
| Operation Junction Temperature | 150 | °C |
| Lead Temperature (10s) | 260 | °C |
| Storage Temperature | -55~150 | °C |
| θ _{JA} | 90 | °C/W |
| θ」c | 45 | °C/W |

Note 1: Stresses above those listed Absolute Maximum Ratings may cause permanent damage to the device.

Note 2: The maximum allowable power dissipation is a function of the maximum junction temperature T_{J(MAX)}, the junction to ambient thermal resistance 0JA, and the ambient temperature TA. The maximum allowable continuous power dissipation at any ambient temperature is calculated by PD(MAX)=(TJ(MAX)-TA)/0JA. Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.

Recommended Operation Conditions⁽³⁾

| Symbol | Value | Unit |
|------------|---------|------|
| VCC to VSS | 5~35 | V |
| Tj | -40~125 | °C |

Note 3: The device is not guaranteed to function outside of its operating conditions.

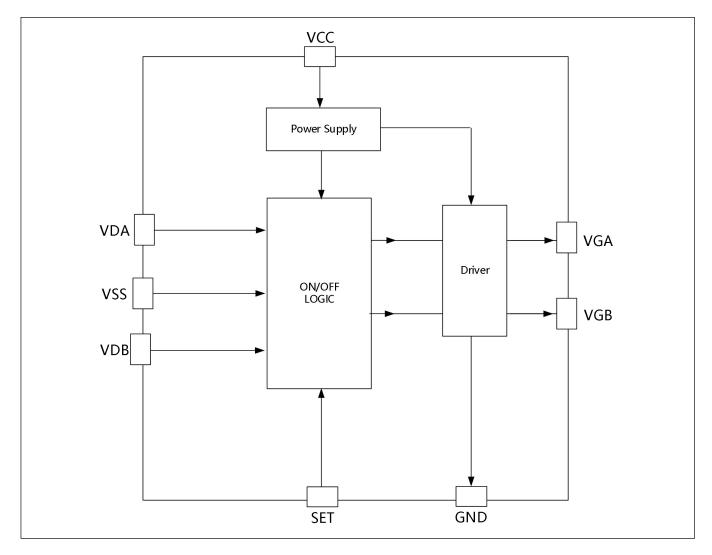
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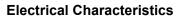
Block Diagram



Pin Definition

| Pin No. | Pin Name | Function Description | | | | |
|---------|----------|---|--|--|--|--|
| 1 | VGA | Gate Driver Output for Channel A. | | | | |
| 2 | GND | IC Power Ground. | | | | |
| 3 | SET | V_{th_off2} set pins , If the voltage is less than 0.35V, enter the Disable mode | | | | |
| 4 | VDA | Drain Sense Input for Channel A. | | | | |
| 5 | VSS | Used as reference for VDA and VDBvoltage sampling | | | | |
| 6 | VDB | Drain Sense Input for Channel B. | | | | |
| 7 | VCC | IC Power Supply, VCC up to 35V. | | | | |
| 8 | VGB | Gate Driver Output for Channel B. | | | | |

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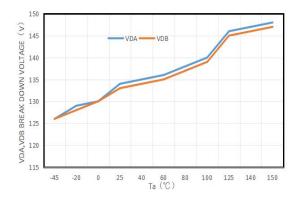


Condition: VCC=12V, TJ=25°C. (unless otherwise noted)

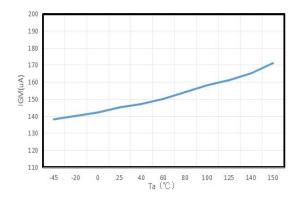
| Parameter | Symbol | Test Conditions | Min | Тур. | Max | Unit |
|---------------------------------|------------------------|---|-------|------|-------|-------|
| Supply Voltage(VCC) | • | · | | | • | • |
| VCC voltage range | V _{CC-Range} | | 4.83 | | 35 | V |
| UVLO(OFF) | V _{CC-on} | | 4.37 | 4.6 | 4.83 | V |
| UVLO Hysteresis | V _{CC-hys} | | 0.31 | 0.35 | 0.39 | V |
| VCC Operating current | lcc | CLOAD = 4.7nF, FSW = 100kHz | 12 | 15.5 | 19 | mA |
| VCC Quiescent operation current | lq | IC Enable without Gate Driver | 1.8 | 2.3 | 2.8 | mA |
| Light Load Mode Current | I _{GM} | Under Light Load Mode | 110 | 150 | 190 | uA |
| Control Circuitry(VDA,VDB, VSS |) | · | | | | |
| Turn on threshold | V _{th_on} | V _{cc} =12V | -210 | -170 | -130 | mV |
| Vds Regulation threshold | V _{th-off2} | | -26 | -20 | -14 | mV |
| Turn off threshold | $V_{\text{th-off}}$ | | 41 | 48 | 55 | mV |
| Turn-on Delay@Heavy Load | T _{don} | T _{GM} <t<sub>GM_EXIT</t<sub> | 72 | 100 | 130 | ns |
| Turn-on blanking time | Tbon | C _{LOAD} =4.7nF | 0.4 | 0.8 | 1.2 | us |
| Turn-off blanking time | T _{boff} | C _{LOAD} =4.7nF | 1.2 | 1.6 | 2 | us |
| Inter lock time | T _{interlock} | Guaranteed by design | | 200 | | nS |
| Light Load Control | • | · | | | • | • |
| Turn off threshold | V _{th-b} | Enable after T _{bon} | 1.6 | 2 | 2.4 | V |
| Entry Time for Light-Load | T _{GM-ENT} | | 34.5 | 45 | 56.5 | us |
| Exit Time for Light-Load | T _{GM-EXIT} | | | 1 | | Cycle |
| IC Enable (SET) | • | · | | | • | • |
| IC Disable | V _{IC-DIS} | | 0.26 | 0.35 | 0.45 | V |
| Gate Driver(GATE) | | · | • | | | • |
| Vg (high) | | Vcc=12V~35V | 10 | 11.5 | 13 | V |
| Vg (low) | | VG sink 100mA | 0.035 | 0.06 | 0.085 | V |
| Maximum source current | ISOURCE | Guaranteed by design | | 200 | | mA |
| Pull-down impedance | I _{Sink} | VG sink 100mA | 0.35 | 0.6 | 0.85 | Ω |
| · | | Vda=Vsa, Cload=1nF, Rgate=0 Ω , Vgs=2V | 20 | 30 | 40 | |
| Turn-off total delay | T _{D-Gateoff} | V _{DA} =VSA, C _{LOAD} =4.7nF, R _{GATE} =0 Ω , V _{GS} =2V | 30 | 45 | 60 | ns |
| In-Chip OTP | | · | · | | | |
| OTP Enter | T _{OTP} | Guaranteed by design | 145 | 160 | 175 | °C |
| OTP Exit | T _{OTP-hys} | Guaranteed by design | 10 | 20 | 30 | °C |

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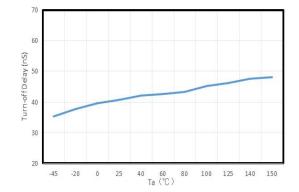
Typical Performance Characteristics VDA,VDB Breakdown Voltage vs. Temperature



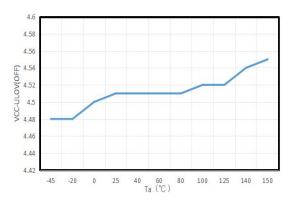
Light Load Mode Current vs. Temperature (VCC=24V)



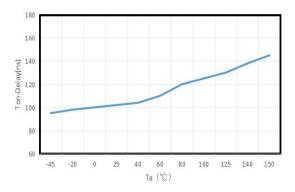
Turn-Off Delay vs. Temperature(CLOAD = 4.7nF)



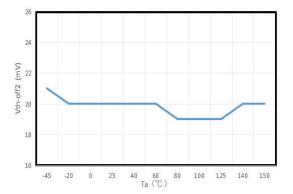
VCC UVLO(OFF) vs. Temperature



Turn-On Delay vs. Temperature(CLOAD = 1nF)



Vds Regulation threshold (VSS - VD) vs. Temperature



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Function Description

The WS2994A is a dual-channel controller for rectifier on the output side of the half-bridge LLC resonant converter, which supports CCM, CrCM and DCM and automatically realizes optimal control. The WS2994A has simple periphery and reliable protection. The following chapters introduce its various functional modules in detail.

Start-Up and Under-Voltage Lockout (UVLO)

The WS2994A VCC withstand up to 35V.When VCC voltage is under UVLO threshold,WS2994A enter in sleep mode and keep the VGA&VGB low. When VCC rises above UVLO threshold, IC starts operating.

Enable(SET)

If the SET pin voltage is less than 0.35V, WS2994A will turn off the driver output, and the IC working current is less than 140 uA. When the SET signal is pulled up again, the drive signal can only resume work when the next rectification cycle arrives.

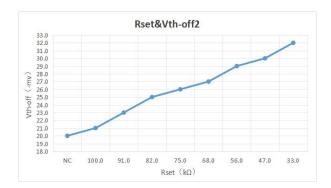
Programmableregulation threshold (SET)

With the SET pin resistance, the value of V_{th_off2} can be fine-tuned. When Rset $\geq 100K\Omega$, V_{th_off2} is -20mV. When Rset <100K Ω , the value of V_{th_off2} decreases linearly and can be adjusted to a maximum of 10mV. The SET pin needs to connect a ceramic capacitor to GND to filter the noise; The larger the capacitance of the SET pin, the better the filtering effect, but the starting time will be longer, and these both sides need to be taken into account; General recommended value: 10nf.

It is recommended that the SET pin resistor value not be less than $33K\Omega$. If the resistance value is less than $33K\Omega$, WS2994A has the risk of turn off the driver output, the chip will enter the energy saving mode.

The following chart shows the Vth-off2 thresholds for different resistance values:

| Rset $(K\Omega)$ | NC | 100.0 | 91.0 | 82.0 | 75.0 | 68.0 | 56.0 | 47.0 | 33.0 |
|------------------|------|-------|------|------|------|------|------|------|------|
| Vth-off2(-mv) | 20.0 | 21.0 | 23.0 | 25.0 | 26.0 | 27.0 | 29.0 | 30.0 | 32.0 |



First on-cycle blanking

After the IC is enabled, or when exiting the energy saving mode, in order to prevent the SR from being turned on during the body diode on and prevent the pass-through phenomenon caused by MOSFET, the IC will shield the first on-tube cycle, and the next on-off cycle will begin to enter the normal MOSFET on-off control.

MOSFET ON/OFF control

Vds drops blew V_{th_on} when current pass through parasitic body diode of MOSFET, IC will output driver signal after T_{don} delay, which is shown in Figure 1.

When the MOSSFET is turned on, the Tbon will be maintained for a period of time, called the turn on shielding time (about 0.9us), to prevent false shutdown caused by ringing.

When the MOSFET Is turned on, the voltage Vds at both ends of the MOSFET follows the secondary current Is. As the current flowing through the switch decreases,When the Vds forward voltage drop exceeds V_{th_off2} (be programmed from -20mV to -32mV), a larger internal pull-down current source takes effect, and the driving voltage decreases with fa larger slope. As the Vds forward voltage drop continues to rise to the shutdown threshold V_{th_off} , the internal pull-down takes effect and the Gate drive voltage is pulled to 0V after a very short shutdown delay. During the Tbon time, the value of

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 V_{th_off} will be adjusted to +90mV to ensure that the Gate driver can still be turned off during the Tbon time to ensure safety in some extreme cases.

In CCM mode, this feature keeps the gate voltage at a very low level when the SR MOSFET is turned off, increasing the turn-off speed.

When the Gate of driver is turned Off, the blanking time starting to be counted, the gate driver remains off for the Tboff time.

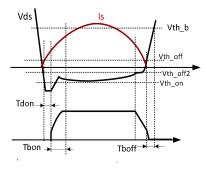


Figure 1 ON/OFF control logic

Burst-mode control

In order to avoid the pre-LLC system being in burst-mode, which would cause the secondary synchronous rectifier controller to turn on incorrectly, the WS2994A has a patented control circuit built in. When WS2994A detects that the system enters Burst-mode, it will increase the drive delay and decrease the drive current. In addition to the two mechanisms mentioned above, WS2994A also adds that the system does not send driver signals in the first cycle after exiting from burst-mode, and outputs driver signals in the next cycle.

Channel Interlock

The WS2994A has a dual-channel driver interlock function, which can prevent the straight-through between the two rectifier MOSFET on. When one of the drive channels is off, its driver will keep in off state until the other channel drive is turned off.

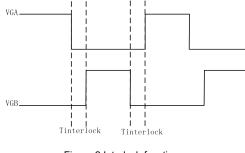


Figure 2 Interlock function

Thermal Shutdown

When the junction temperature of the IC is higher than the over-temperature protection threshold, the driver will be shutdown and enters in OTP mode. And IC will exit OTP mode when the junction temperature decrease 20 degree.

PCB Layout Guidelines :

1, VDA and VDB respectively form two detection loops with

VSS,VDA/VSS, VDB/VSS as close as possible to each MOSFET (drain/source), the loop is as small as possible; The two detection loops are separated as far as possible and drawn as two independent small loops.

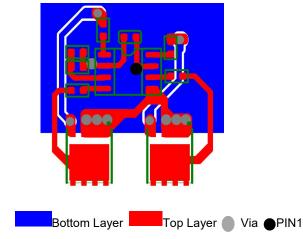
2, Place a decoupling capacitor no smaller than $1\mu F$ from VDD to PGND close to the IC for adequate filtering.

3, SET pin needs to add a capacitor to filter out interference; Capacitance and resistance as close to the pin as possible.

4, It is highly recommended to place the driver's sensing loop trace away from the power loop trace. The sensing loop trace and power loop trace can be placed on different layers to keep them separate from each other.Do not place the driver IC inside the power loop; this may affect MOSFET voltage sensing.

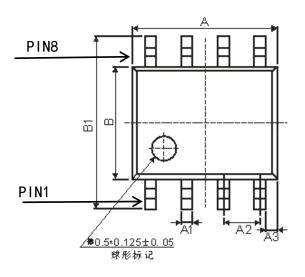
5, The VSS pin must be connected to the SR MOSFET source pin as much as possible. It minimizes errors caused by voltage difference on PCB tracks because of parasitic inductance in combination with large dl/dt values.

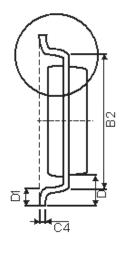
Layout Example:

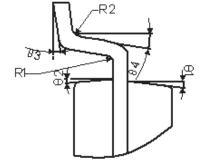


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SOP-8 Package Dimension





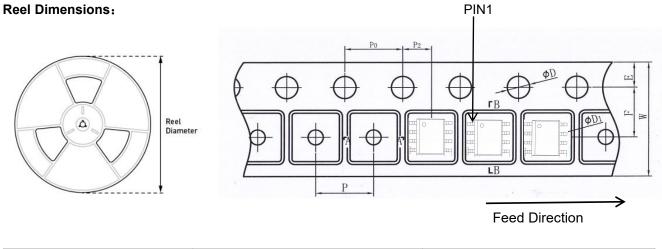




| | Winsemi | | | | | |
|-----------|-----------|-------------------|-----------|-------------|--|--|
| Cumula al | Dimensior | ns in Millimeters | Dimension | s in Inches | | |
| Symbol | Min | Мах | Min | Мах | | |
| Α | 4.70 | 5.10 | 0.185 | 0.201 | | |
| В | 3.70 | 4.10 | 0.146 | 0.161 | | |
| С | 1.30 | 1.50 | 0.051 | 0.059 | | |
| A1 | 0.35 | 0.48 | 0.014 | 0.019 | | |
| A2 | 1 | .27TYP | 0.05 | TYP | | |
| A3 | 0.345TYP | | 0.014 | 4TYP | | |
| B1 | 5.80 | 5.80 6.20 | | 0.244 | | |
| B2 | 5 | .00TYP | 0.19 | 7TYP | | |
| C1 | 0.55 | 0.70 | 0.022 | 0.028 | | |
| C2 | 0.55 | 0.70 | 0.022 | 0.028 | | |
| C3 | 0.05 | 0.225 | 0.002 | 0.009 | | |
| C4 | 0.203TYP | | 0.008 | втүр | | |
| D | 1.05TYP | | 0.04 | 1TYP | | |
| D1 | 0.40 | 0.80 | 0.016 | 0.031 | | |



Shipping Packing Information:



| Reel Diameter | Carrier Tape Width | Carrier Tape Pitch |
|---------------|--------------------|--------------------|
| 13in | 12±0.1mm | 8±0.1mm |

Packing quantity specification

| Part Number | Package Description | Quantity/Reel | Reel/Box | Box/Carton | Quantity/Carton |
|-------------|---------------------|---------------|----------|------------|-----------------|
| WS2994A | SOP-8 | 4000 | 2 | 5 | 40000 |

NOTES:

1. Please recognize the company's trademark when purchasing, and contact the company headquarters if you have any questions.

2. Please do not exceed the absolute maximum rating of the device during circuit design, otherwise it will affect the reliability of the whole machine.

3. This manual is subject to version change without further notice.

CONTACT:

Winsemi Microelectronics Co.,Ltd.

ADD:Room 3101-3102, 31F, Building 8A, Shenzhen International Innovation Valley, Nanshan District, Shenzhen, CN.

PostCode:518000

Tel:86-0755-82506288 WebSite:www.winsemi.com

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